

# **AXIAL LEADED SILICON RECTIFIER DIODES**

VOLTAGE RANGE: 1650V CURRENT: 2.5 A

# **Features**

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability

# **Mechanical Data**

Case: DO-201AD, Molded Plastic

Terminals: Plated Leads Solderable per

MIL-STD-202, Method 208

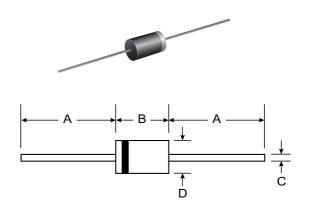
Polarity: Cathode Band

Weight: 1.2 grams (approx.)

Mounting Position: Any

Marking: Type Number





DO-201AD				
Dim	Min	Max		
Α	25.40	_		
В	7.20	9.50		
С	1.20	1.30		
D	4.80	5.30		
All Dimensions in mm				

## Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	BY228GP	Unit
Maximun Non-Repetitive Peak Reverse Voltage		Vrsm	1650	V
Maximun Repetitive Peak Reverse Voltage		Vrrm	1650	V
Maximum Continuous Reverse Voltage		Vr	1500	V
Maximum RMS Voltage		Vrms	1050	V
Maximum DC blocking Voltage		Vdc	1500	V
Maximum Average Forward Rectified Current 0.375" (9.5mm) lead length at Ta =50°C		If(av)	2.5	А
Non-Repetitive Peak Forward Surge Current at t=10ms half sinewave		Ifsm	50.0	А
Maximum Instantaneous Forward Voltage at 5.0A		Vf	1.50	V
Maximum DC Reverse Current at rated DC blocking voltage	Ta =25°C Ta =150°C	lr	5.0 150.0	μА
Typical Reverse Recovery Time	(Note 1)	Trr	1000	nS
Typical Thermal Resistance	(Note 2)	Rth(ja)	75.0	K/W
Storage and Operating Junction Temperature		Tstg, Tj	-65 to +175	°C

#### Note:

- 1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A
- 2. Device mounted on an epoxy-glass printed-circuit board, 1.5mm thick



### **RATINGS AND CHARACTERISTIC CURVES BY228GP**

